Polycrystalline silicon is an essential component in the current generation of solar cells, next generation batteries, and semiconductor devices. In particular the electronic properties of silicon and polycrystalline silicon have been the subject of many studies based on the application of p and n doped silicon in semiconductor devices. In addition, the electromechanical properties of silicon also prove immensely interesting given the observance of giant piezoresistance in silicon nanowires. Interfaces such as grain boundaries and phase boundaries are a component of the material design space which have a significant effect on the electrical and mechanical properties of a polycrystalline material [1] and thus should be evaluated appropriately so as to enhance the functional properties of a material. (Poly xl Silicon is an important material…find uses and support with references), electrical and mechanical properties.

Grain boundary orientations are generally defined by five macroscopic degrees of freedom that describe the relative orientation of the grains and the alignment of the interface plane. However, at the microscale, there are countless microscopic degrees of freedom that can result in different local atomic interface structures. As a result, the sampling of all combinations of these microscopic degrees of freedom can rapidly increase the computational cost for even a single grain boundary. Previous research has approached the local optimization of interfaces using translational search techniques [5], evolutionary/genetic algorithms [6], and Monte Carlo based sampling [7]. While each of these methods proved relatively useful for a specific set of conditions that were investigated, the scope of these studies was often limited to the investigation of single component metals or to the exploration of ideal thermodynamic stable interfaces. Monte Carlo based optimization, however, has recently shown promise in both exploring polycrystalline ceramics and extracting relevant metastable interface structures [8].

During Monte Carlo based optimization of bicrystal interfaces [8], structures are probed by pseudo-randomly inserting, removing, or replacing individual atoms within the interface regions. To more efficiently probe likely-favorable states, the randomness of these operations is biased based on probabilities tuned by the user at the start of the search. Once an operation type is chosen, the location of the operation is determined based off probabilities defined by the local structure. After each operation, the interface structure is relaxed using a three-step process of quenching, equilibration, and minimization within the framework of classical molecular dynamics. Energetically favorable operations are accepted using a Boltzmann weighted probability, which enables efficient sampling of metastable interface structures along the way to the energetic minimum. Monte Carlo optimization of a single interface structure will often involve thousands of interface operations and produce hundreds of acceptable metastable states. This amount of data generated in these studies opens up opportunities for machine learning methods for accelerated sampling.

In this study, a machine learning model is constructed to efficiently predict the change in the interface energy after an individual Monte Carlo operation. Here we focus on silicon grain boundary data obtained from classical atomistic simulations coupled with descriptor-based machine learning. We show here this approach can accelerate the overall interface optimization by replacing the hand-tuned operation probabilities with one that takes into account the current system configuration. (more approachable, better sentence) The implementation of a statistical and regression-based scheme for the prediction of the energetic properties of silicon grain boundaries is also discussed. We show here that … (one or two key outcomes of this paper). The methodology described herein is applicable to other materials systems such as pure metals and simple one phase substitutional alloys. It can be expanded further to phase boundaries if … (broader impact, with limitations perhaps… two-phase, multiphase acceleration, low energy grain boundaries how will it push mat. Sci further, finite element cluster (multiscale modelling), can these findings be an input to next level up in terms of code, save time, inform phase field and finite element. )

Read Srolovitz paper….

Figures with story board, grain boundary schematic -> flow chart -> results…(predicted vs. true), learning curves, efficiency of models i.e. improvement in MC codes.

Methodology: